

Attachment E - Varian Medical Systems Disclosure of Invention

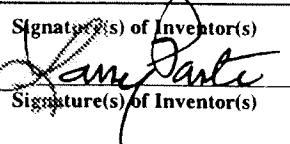
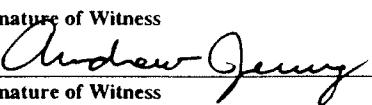
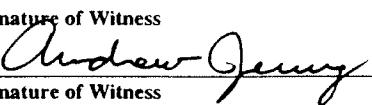
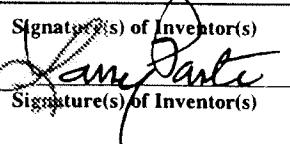
• Disclosure of Invention

D2002-027

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RECEIVED
Form should be carefully
represented. M. E. 23 2002

<p>Descriptive Title of Invention: Reducing Dark Current Of Photoconductors Using Heterojunctions That Manufacture High X-ray Sensitivity</p> <p>LEGAL DEPARTMENT</p> <p><i>List all inventors, include full middle names. Use attached sheet if more than one inventor.</i></p>							
<p>Name & Title of Inventor(s) Larry Partain, Advanced Tech Mgr</p>		<p>Badge # 38590</p>	<p>Home Telc phone# 650-941-7531</p>	<p>Country of Citizenship USA</p>			
<p>Home Address/Street 590 Milverton Road</p>		<p>City Los Altos</p>	<p>State CA</p>	<p>Zip 94022</p>			
<p>Business Unit Name Ginzton Technology Center</p>		<p>Business Unit Address 2599 Garcia, Mountain View, CA 94043</p>					
<p>Stage of Development(*see definitions)</p>		<p>Date (Mo/Yr)</p>	<p>Location</p>	<p>Identify Persons or Supporting acts Stated in 4.A-E</p>			
<p>A. First sketch or drawing</p>							
<p>B. First disclosure to others</p>							
<p>C. First written description</p>							
<p>D. Completion of first model or full size device</p>							
<p>E. first actual reduction to practice*</p>							
<p>List project # and other pertinent notebook entries, photographs, reports, drawings VIP Project AH109341</p>							
<p>If the invention was disclosed outside of Varian, identify the individuals, the companies or activities they represent, and the date of disclosure. Under NDA to Kanai Shah, Paul Bennett & Mike Squillante of RMD on June 27, 2002</p>							
<p>List any known public use, publication, or oral presentation of the invention, sale or offer for sale(*see definitions)</p>							
<p>No Yes Date Persons, Companies or Pub</p>							
<p>A. Sold</p>							
<p>B. Offered for Sale as part of a Product*</p>							
<p>C. Offered for Sale in development program*</p>							
<p>D. Described in Publication*</p>							
<p>E. Submitted to Publication</p>							
<p>F. Placed in public use*</p>							
<p>G. Used in a product in public use</p>							
<p>H. Orally presented</p>							
<p>List dates and details of activities of 7.A-H if scheduled in future</p>							
<p>Related Government Contract(s). Did your job assignments involve work under a Government contract related to the inventive subject matter at the time the invention was...</p>							
<table border="1"> <tr> <td>No</td> <td>Yes</td> <td>Contract No.</td> </tr> </table>					No	Yes	Contract No.
No	Yes	Contract No.					
<p>Conceived <input type="checkbox"/> <input type="checkbox"/> <input type="checkbox"/></p>							
<p>First successfully tested <input type="checkbox"/> <input type="checkbox"/> <input type="checkbox"/></p>							
<p>See page 2 (Section 10 Instructions) The completed description should be signed by the inventor(s), and then read and signed by a technically competent witness, using the statement 'DISCLOSED TO AN UNDERSTOOD BY ME THIS ____ DAY ____ OF ____ 20 ____.' Drawings, sketches, photographs, reports, if available, may for a part of the disclosure, and reference thereto can be made to complete this description.</p>							
<p>Recommended Security Classification of the invention</p>							
<p><input type="checkbox"/> Unclassified <input type="checkbox"/> Confidential <input type="checkbox"/> Secret <input type="checkbox"/> Other _____</p>							
<p>Signature(s) of Inventor(s)</p>		<p>Date</p>	<p>Signature of Witness</p>	<p>Date</p>			
		<p>7/23/02</p>		<p>7/23/02</p>			
<p>Signature(s) of Inventor(s)</p>		<p>Date</p>	<p>Signature of Witness</p>	<p>Date</p>			
		<p>7/23/02</p>		<p>7/23/02</p>			



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Descriptive Title of Invention: Reducing Dark Current Of Photoconductors Using Heterojunctions That Maintain High X-ray Sensitivity

List all inventors, include full middle names. Use attached sheet if more than one inventor.

Name & Title of Inventor(s) Mike Green MICHAEL CURZON GREEN <small>(SENIOR SCIENTIST)</small>	Badge # 20193	Home Telephone# 650.850 USA 7921	Country of Citizenship U.K.
--	------------------	-------------------------------------	--------------------------------

Home Address/Street 4055 MANZANA LANE	City PALO ALTO	State CA	Zip 94306
--	-------------------	-------------	--------------

Business Unit Name Ginzon Technology Center	Business Unit Address 2599 Garcia, Mountain View, CA 94043
---	--

Stage of Development(*see definitions)	Date (Mo/Yr)	Location	Identify Persons or Supporting acts Stated in 4.A-E
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A. First sketch or drawing			
B. First disclosure to others			
C. First written description			
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E. first actual reduction to practice*			

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	No	Yes	Date	Persons, Companies or Pub
A. Sold				
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C. Offered for Sale in development program*				
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H. Orally presented				

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Recommended Security Classification of the invention

Unclassified Confidential Secret Other _____

Signature(s) of Inventor(s)

MC Green

Date

7-23-02

Signature of Witness

Andrew Jenny

Date

7/23/02

Signature(s) of Inventor(s)

Date

Signature of Witness



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List all inventors, include full middle names. Use attached sheet if more than one inventor.			
2	Name & Title of Inventor(s) Steve Bandy	Badge # 01793	Home Telephone# USA 408 7324505
	Home Address/Street 590 Middlebury Dr.	City Sunnyvale	State CA
	Business Unit Name Ginzton Technology Center	Business Unit Address 2599 Garcia, Mountain View, CA 94043	
	Stage of Development(*see definitions)	Date (Mo/Yr)	Location
	A. First sketch or drawing		
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Signature(s) of Inventor(s) <i>Andrew Jenny</i> Date <i>7/23/02</i>		Signature of Witness <i>Andrew Jenny</i> Date <i>7/23/02</i>	
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List all inventors, include full middle names. Use attached sheet if more than one inventor.				
2	Name & Title of Inventor(s) George Zentai	Badge # 30811	Home Telephone# 650 559 USA 8555	Country of Citizenship HUNGARY
	Home Address/Street 1054 Blackfield Way	City Mountain View	State CA	Zip 94040
Business Unit Name	Ginzton Technology Center	Business Unit Address 2599 Garcia, Mountain View, CA 94043		
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Signature(s) of Inventor(s) 	Date 7/23/02	Signature of Witness 	Date 7/23/02	
Signature(s) of Inventor(s)	Date	Signature of Witness	Date	

Reducing Dark Current Of Photoconductors Using Heterojunctions That Maintain High X-ray Sensitivity

Patent Disclosure

Inventors:

**Mike Green, Steve Bandy,
George Zentai & Larry Partain**
Varian Medical Systems

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medical systems

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Date: 7/23/02 Inventors: *George Zentai Steve Bandy*
Michael C. Green

ginzton technology center

Read & Understood: *Andrew Jeng* Date: 7/23/02

Invention Summary

- Dark current limits the usefulness of high X-ray sensitivity of photiconductor sensors. This dark current can be substantially reduced by using p/n heterostructures of photconductors without the loss of their high sensitivity.

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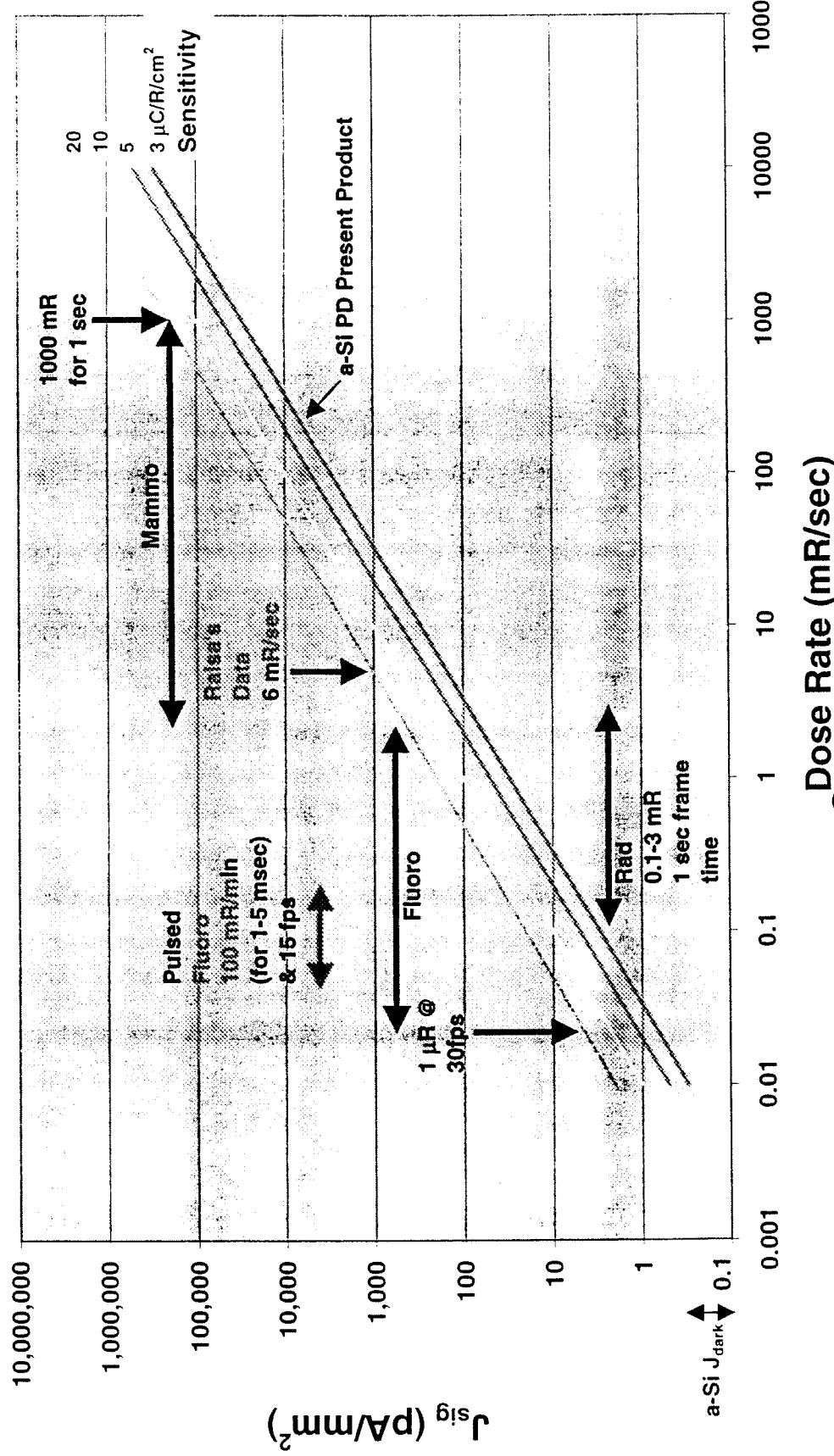
Date: 7/23/02 Inventors: Sam Balow
John B. G. Brown

John B. G. Brown

ginzton technology center
Read & Understood: *Andrew Young* Date: 7/23/01

PC Signal Current Vs Dose Rate

Dark current needs to be lower than signal current



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Date: 7/23/02 Inventors: *Sam Danis*

Michael C. Green
Jeff Bluth

Read & Understood:

Date:

Andrew Jarry 7/23/02

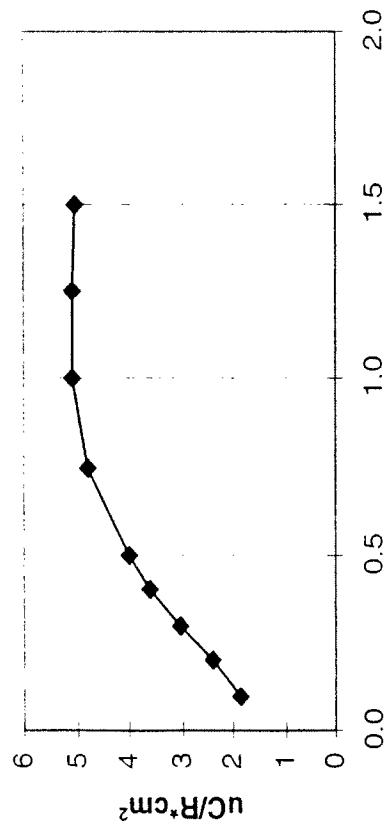
Good Sensitivity Requirements

Bias Of $\sim 0.5 - 1$ V/ μ m

HgI₂

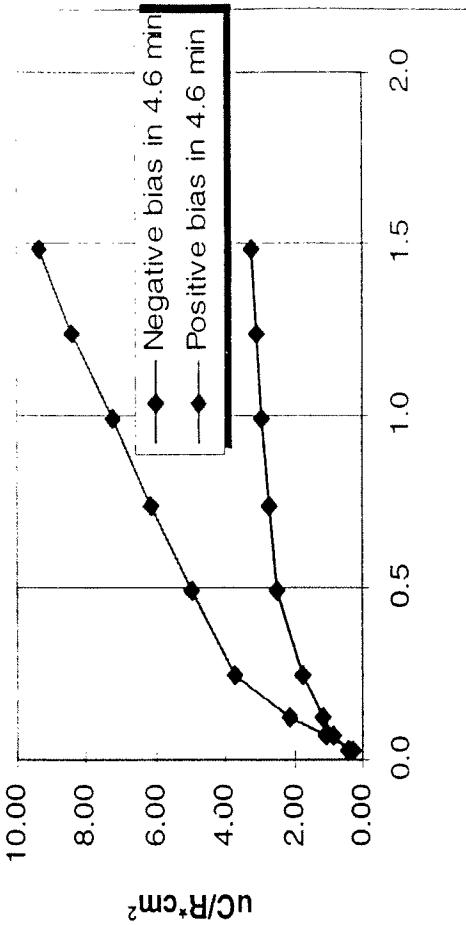
Sensitivity vs. negative bias @ 80 kVp,
1 mA

RTR HgI₂ #7449 contact 7



PbI₂

Sensitivity vs. bias @ 80 kVp, 1 mA
RMD PbI₂ #739 contact 3



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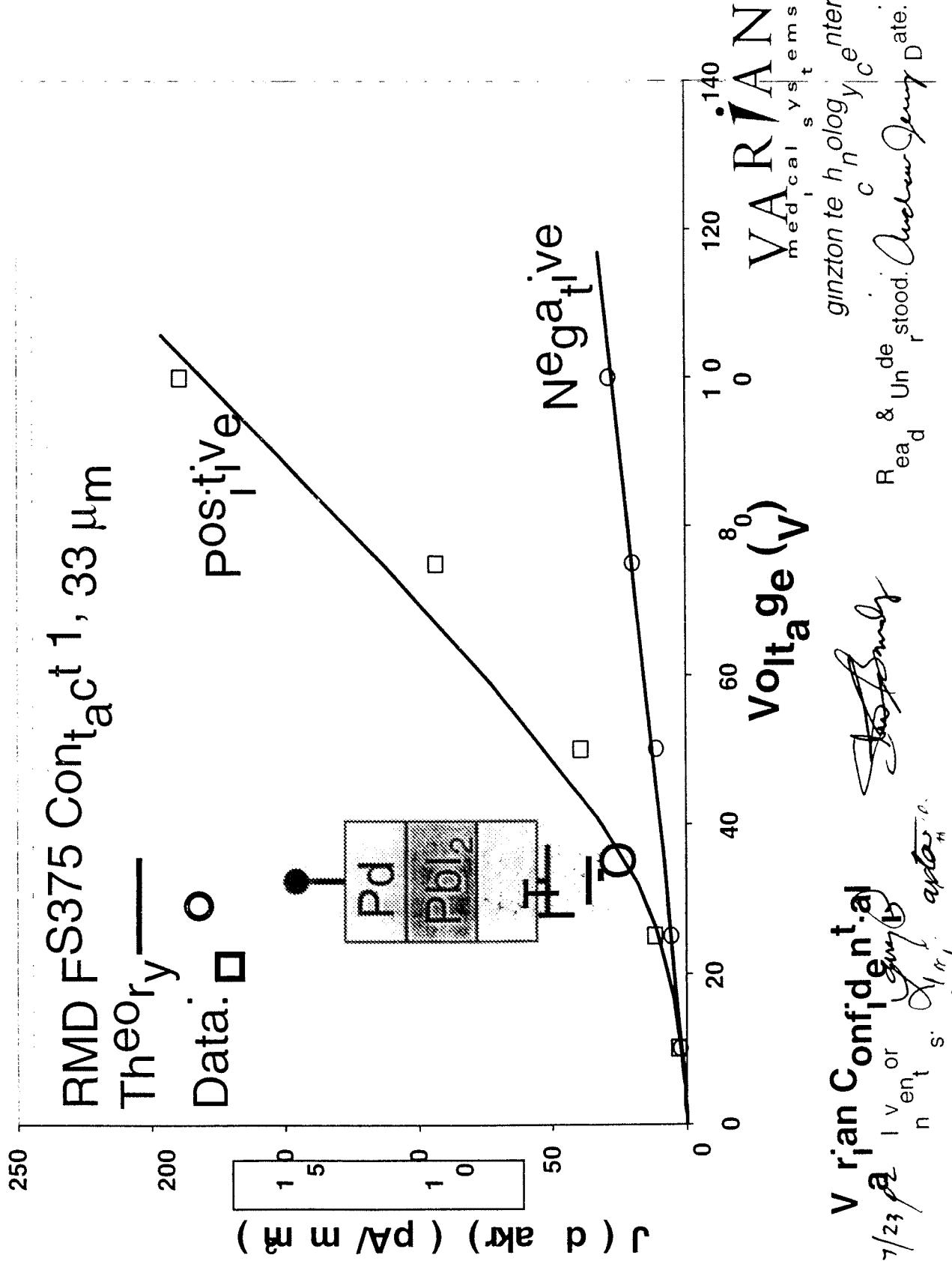
Date: 7/23/01 Inventors: *Sanjiv Patel* *Steve Brink*
David P. Green

Andrew Jeng

ginzton technology center

Read & Understood: *Andrew Jeng* Date: 7/23/01

PbI₂ Dark Current



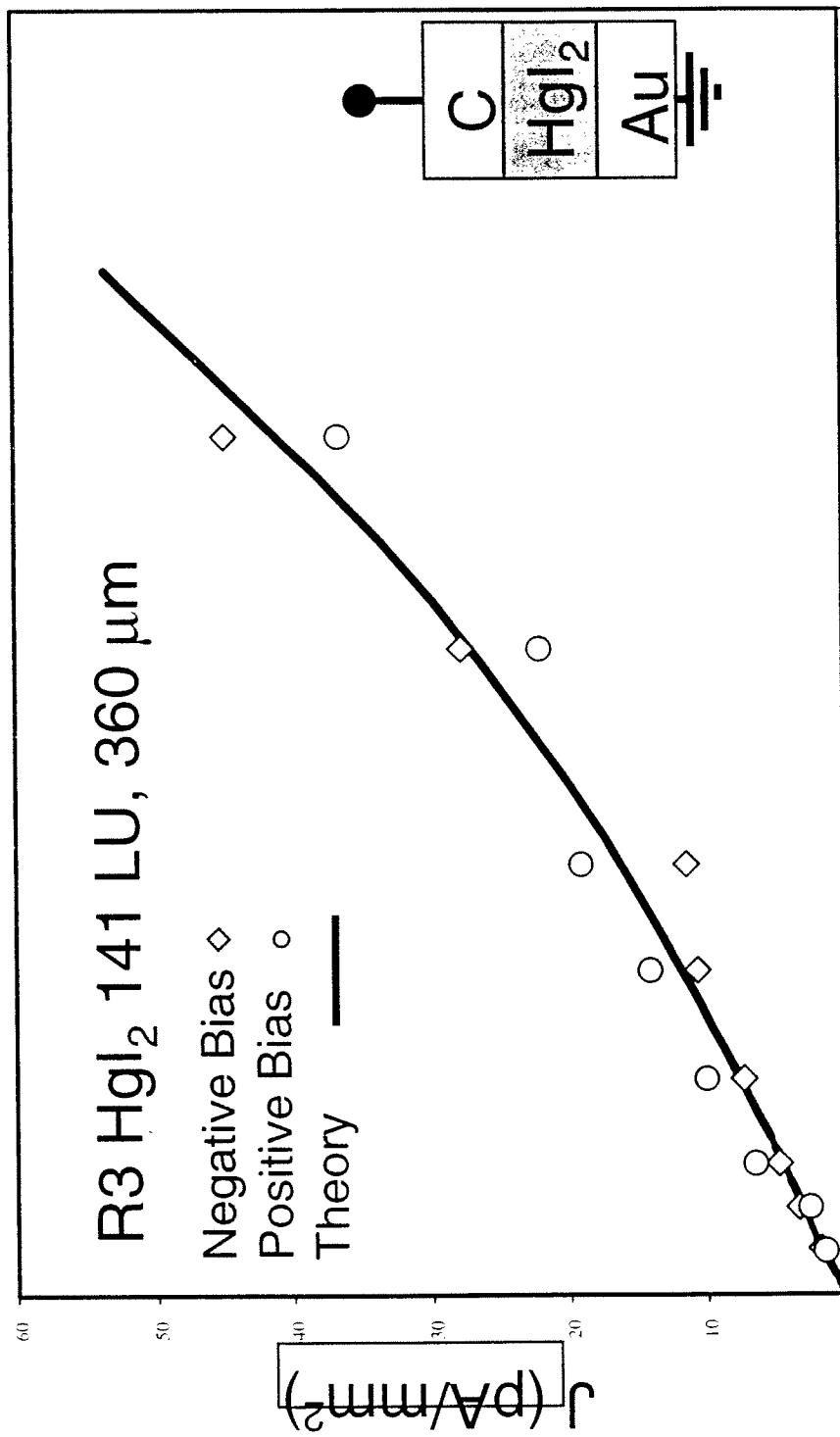
Variation Confidence Interval
Date: 7/23/02

Stability
Date: 7/23/02

Varian Confidence Interval
Date: 7/23/02

Varian Confidence Interval
Date: 7/23/02

HgI₂ Dark Current



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Date: 7/23/02 Inventors: Sam Shuler, *Sam Shuler*, *John Binkley*

John Binkley

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Date: 7/23/02
Understood: *Andrew Young*

Dark Current Limits

$$E = \rho J$$

For $E = 1 \text{ V}/\mu\text{m}$ and $J_{\text{dark}} = 1 \text{ pA}/\text{mm}^2$
 $\rho = 10^{14} \text{ Ohm-cm}$ (Desired thin film value)

$$\begin{aligned} \rho &= 10^{12} \text{ Ohm-cm a-Si} \\ &= 10^{12} \text{ Ohm-cm Se} \\ &= 10^{12} \text{ Ohm-cm PbI}_2 \\ &= 10^{13} \text{ Ohm-cm HgI}_2 \end{aligned} > \text{Single Crystal Values}$$

Polycrystalline thin films ρ unlikely
to exceed single crystal values

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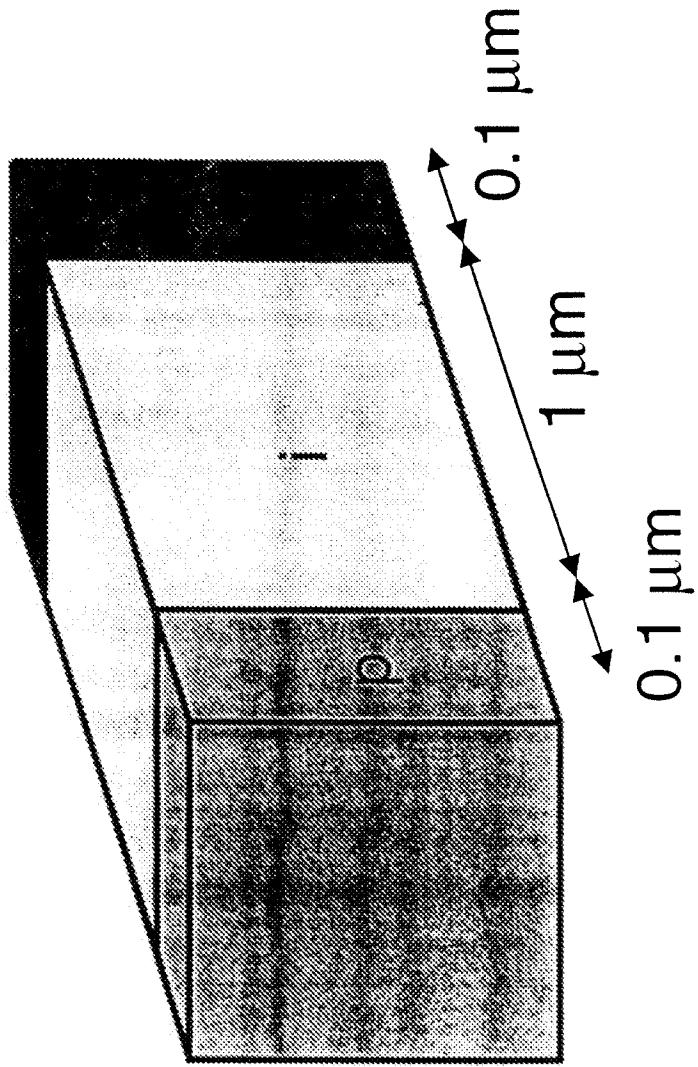
Date: 7/23/02 Inventors: *James Darter* *Jeffrey C. Green*

Jeffrey C. Green
Read & Understood: *Andrew Young* Date: 7/23/02

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Read & Understood: *Andrew Young* Date: 7/23/02

Low Dark Current In a-Si Sensor Arrays



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Read & Understood: *Andrea* Date: 7/23/02

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Date: 7/23/02 Inventors: *Sam Gantman, John S. Gantman*

Heterojunction Structures

- Past experience
 - 1.2 eV p-Cu₂S/2.4 eV n-CdS (0.1-0.3 μ m/30 μ m)
 - Cu compensates “i” region in CdS (\sim 1 μ m)
 - High rectification ratio
 - Good “photodiode”
 - 10% efficient solar cell

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Read & Understood: *Andrew Jeng* Date: 7/23/02

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Date: 7/23/02 Inventors: *Andy Jeng* *Bob Ginn*
7/23/02

Proposed Heterojunction Structures

- 2.3 eV p-PbI₂/2.1 eV n-HgI₂ (sublimated last)
 - Thickness combinations
 - Th₁^cK/Th₁n (e.g. 200 μm/50 μm)
 - Medium/Medium (e.g. 150 μm/350 μm)
 - Medium/Thin (e.g. 40 μm/350 μm or 10 μm/450 μm)
 - Th₁^n/Th₁K (e.g. 40 μm/350 μm)
 - 1.7 eV n_a-Si₁/3 eV p-PbI₂ (e.g. ~0.1 μm/200 μm)
 - 1.7 eV p_a-Si₁/3 eV n-HgI₂ (e.g. ~0.1 μm/350 μm)
 - A_dⁿ V₁^c V_e^r 2_a¹ h a-Si₁
- n_oⁿ end Sn W₁^t
n_aⁿ a p

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m d: c i s y s e m s
gintz of te hñ /
c o o g y c ente'
R ad & Un de rsto d. John Doe
Date: 1/23/02
D^a te: e

ar an Co n_t
1/2 V_o_z Inven n_d
Date: 1/23/02
D^a te: e

Combine With Insulator Layers (or Insulator Alone)

- SiO_2
- $\text{SiO}_{2-x}\text{N}_x$
- Formed by dipix before photiconductor deposition
- Several 100 Angstroms thick

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invention
by *John Schantz* *John Schantz*
and *John Schantz*